C om petition of ferrom agnetism and superconductivity in Sc₃InB

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W e present results of electronic structure calculations for interm etallic perovskite $Sc_3 InB$ with Full(Potential KKR-LDA m ethod. $Sc_3 InB$ is very promising candidate for a new superconductor (related to 8 K M gCN i_2) and can be regarded as a boron (inserted cubic $Sc_3 In$, which is a high (pressure allotropic form of the hexagonal weak ferror agnet $Sc_3 In$. W e predict that cubic $Sc_3 In$ can be also m agnetic, whereas $Sc_3 InB$ having large DOS in the vicinity of E_F exhibits non-m agnetic ground state. Estimation of the electron (phonon coupling for $Sc_3 InB$ gives ' 1. Furtherm ore, the e ect of vacancy in $Sc_3 InB_1$ x and antisite disorder in $Sc_3 (In-B)$ on critical parameters is also discussed in view of KKR (CPA m ethod. All theoretical results support possibility of the superconductivity onset in $Sc_3 InB$. P relim inary experimental m easurem ents established the transition tem perature close to 4.5 K, with a very abrupt change in susceptibility and a correlated drop of the resistivity when cooling down.

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I. IN TRODUCTION

Recent discovery of superconductivity in the intermetallic perovskite MgCN i $_3$ [1] with T $_{\rm c}$ ' 8 K was a great surprise due to large N i contents and this com pound was rather expected to be near ferrom agnetic critical point [2]. It was established that electron {phonon mechanism is responsible for superconductivity in this material, but few details are still not clear. NMR t_1 relaxation tim e experim ents [3] or speci c heat m easurem ents [4] have resulted in typical behaviors, supporting s{wave type pairing with electron {phonon coupling constant 0:8. Conversely, rather unconventional behaviors have been observed in other experiments (e.g. increase of critical tem perature with pressure [5] or unusual low {tem perature behavior of London penetration depth $_{\rm L}$ (T) [6]), which can be partly connected with spin uctuations likely appearing due to vicinity of ferrom agnetism . M oreover, com plex dynam ical properties of this superconductor, as e.g. soft {m ode behaviors and instability of N i vibrations [7], [8], m ake its theoretical analysis quite cum bersom e.

In this paper we report on predictions of superconductivity in related $Sc_3 InB$ compound, which also seems to be close to magnetism limit due to weak ferrom agnetic properties of $Sc_3 In$. It was already revealed that $Sc_3 InB$ crystallizes in a perovskite structure (space group Pm – 3m, CaT iO₃ type) with lattice constant a = 4.56 A [10]. However, the same number of valence electrons of boron and indium elements may give rise to lattice instabilities and In/B antisite defects are plausible.

II. THEORETICAL STUDY

Electronic structure calculations were performed by Full Potential KKR method [11], [12] within the LDA framework employing von Barth-Hedin formula for the exchange-correlation potential. Figure 1 presents electron density of states (DOS) in Sc3 InB compound. The Ferm i level (E_F) is located on the decreasing slope of large DOS peak with the $n(E_F)$ value being as large as ' 90 states/Ry. The main contributions can be attributed to Sc (d{states) and In (p{states) (see Tab. I). N otew orthy, appearance of a large D O S peak close to E $_{\rm F}$, com ing essentially from transition m etalN i{d states, was also characteristic of electronic structure of M gC N i (M g contribution was negligible) [2],[9]. The Sc3 InB case is not sim ilar, since In plays more active role in form ation of electronic states near E $_{\rm F}\,$ due to one electron m ore on p{shell.

a. Predictions of superconductivity in Sc₃InB The electron {phonon coupling strength was estimated by calculating M cM illan {H op eld parameters [13] from G aspari{Gyor y formulas [14] { [16] within Rigid M ufn T in Approximation (RM TA). The electron {phonon coupling constant was then calculated from relation: = $i_i = m_i h!_i^2 i$, where i corresponds to atom s in the

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TABLE I: Properties of Sc₃InB.n (E_F) is given in Ry ¹/atom, in mRy/ a_B ²/atom, ! in meV, M h! ²i in mRy/ a_B ².

A tom	n(E _F)	n_s (E $_F$)	$n_{\rm p}$ (E $_{\rm F}$)	n_{d} (E $_{\rm F}$)	n_{f} (E $_{F}$)		sp	pd	df	Р <u>.</u> h!²i	M h!²i	
Sc	20.26	0.06	2.34	16.98	0.88	18.6	0.0	4.7	13.3	18.5	75.7	0.74
In	18,28	0.04	16.72	1.16	0.32	1.5	0.0	1.5	0.0	18.5	193.4	0.01
В	6.72	0.02	5.92	0.42	0.36	34.3	0.0	34.3	0.0	58.3	180.9	0.19

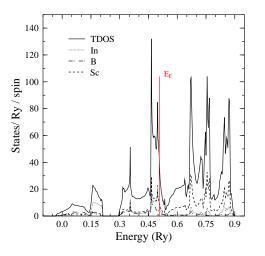


FIG.1: Total electron DOS in Sc_3 InB.

unit cell. The h! $_{1}^{2}$ i parameter was derived from phonon DOS F (!) [22], computed for minimum {energy lattice constant $a_{0} = 8.610 a_{B}$ ($1 a_{B} = 0.529 A$) within Density Functional Perturbation Theory, using the PW scfpackage [17].

In order to take into account the markedly di erent m asses of Sc, In and B atom s, phonon spectrum was analyzed while focusing on two parts: low frequency region with predom inantly In and Sc modes (peak at 13 m eV comes from at acoustic In modes) and high frequency region with B vibrations (above 50 m eV). Noteworthy, sim ilar separation of phonon DOS was earlier observed experimentally in MgCN i₃ [8]. Values of h! $_{1}^{2}$ i used next to estimate , were calculated separately for both regions (with cut line at 50 m eV): h! $_{1}^{2}$ i for Sc and In are taken to be equal, and represent the low {frequency part, while h! $_{B}^{2}$ i was taken from high frequency part of the spectrum. Results and estimation of $_{1}$ are presented in Table I, total electron {phonon coupling constant is = 0.94.

U sing M cM illan form ula [13] for critical tem perature and applying typical value of C oulom b pseudopotential 2 = 0.13, we got $T_{\rm c}$ ' 12 K (we used h! i=1.2 with h! i= 19.5 m eV instead of !_{\rm D} =1.45 in M cM illan form ula in practical computations). Both and $T_{\rm c}$ values belong to moderate regime of superconducting parameters within the RM TA model, and are higher than in M gCN i₂.

We can also notice advantageous trend of electron { phonon coupling in $Sc_3 InB$ if comparing with M gC N i_3 superconductor. Our KKR calculations for M gC N i_3 showed that N i has the largest M cM illan {H op eld pa-

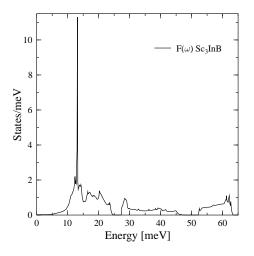


FIG.2: Phonon DOS in Sc_3 InB.

ram eter: $_{N i} = 20 \text{ m Ry/a}_B^2$ with respect to other atom s ($_C = 9 \text{ m Ry/a}_B^2$, $_{M g}$ - negligible). The value of $_{Sc}$ in Sc₃InB is similar to $_{N i}$ in MgCN i₃ but $_B$ is over three times larger than $_C$ (both In and Mg contributions are much smaller). In view of recent C isotope e ect measurements [18] (very large $_C = 0.54 \text{ coe} - \text{cient}$) and bearing in mind a particular sensitivity of T_c on the carbon concentration, one can conclude that both C and N i sublattices are important in superconductivity of MgCN i₃. In view of these criterion T_c in Sc₃InB can be expected higher than in MgCN i₃.

b. Magnetic properties of Sc3 In It seems that instability towards magnetism may also be present in $Sc_3InB_{1 \times}$ compound. First, we have studied electronic structure of both allotropic phases of Sc₃ In. The hexagonal compound (NigSn-type, a = 6.42 A, c = 5.18 A [10]) is well{known weak itinerant ferrom agnet, while the cubic compound ($Cu_3Au\{type, a = 4:46 A, syn$ thesized under high pressure [10]) has not been yet investigated to our know ledge. Present KKR calculations showed that both allotropic forms of Sc3 In should exhibit magnetic ground state supported by magnetic moment on Sc atom s, i.e. $0.26_{\rm B}$ (hexagonal phase) and 0.27 _B (cubic phase). We should rem ind that experimentally observed magnetic moment is much weaker $(0.05 \text{ }_{\text{B}} \text{/Sc in hexagonal phase})$, as already underlined in the previous LAPW calculations [19]. Besides, the superconductor{to{ferrom agnet transition can appear in Sc₃InB_{1 x} if varying B content (KKR-CPA computations are in progress). Thus, as already suggested in

M gCN is [2], [7] one can expect that the proximity of ferrom agnetic quantum critical point (resulting in enhanced spin uctuations) may probably compete with superconductivity.

III. EXPERIMENTAL ANALYSES

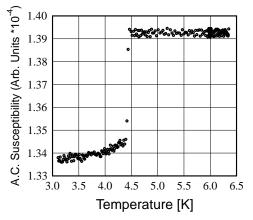
Α 1.5 g sample was rst prepared by arc melting under high purity argon atmosphere (99.9995) starting from the appropriate proportions of the elements (purity > 99.95) to obtain the Sc_3 InB formula. The resulting small ingot was melted several times in order to insure hom ogeneity. Pieces of the ingots were made by using a metal mortar, and inspection by using an opticalm icroscope reveals the bright and hom ogeneous aspect of the fractured surfaces. Then, XRD patterms were recorded at $_{\rm K}$ (C u) using a B ragg-B rentano di ractom eter equipped with a backscattering pyrolitic graphitem onochrom ator. The di raction pattern reveals the presence of a dom inant am ount of cubic phase with the addition of a minor impurity. Probably because no annealing procedure was applied, the crystallised state of the sam ple was not of the best and no e ective crystal structure re nem ent was applied. How ever using the PowderCellcode [20], the two main phases were clearly identi ed and a rough determ ination of the cell param eters was made possible. The main phase (70 % vol.) is simple cubic of perovskite type of structure and the second one (30 % vol.) is hexagonal of N is In type of structure (space group $P 6_3 = m m c$). A counting for the large di erence in between the scattering lengths of the p-elements B and In, an estimate of the composition of the main phase was made. All the results are displayed on Table II.

TABLE II: Structure analysis of the m aterial synthesized with the nom inal composition $\operatorname{Sc}_3\operatorname{InB}$.

Compound		Туре	e Cellparam eters [A]			C om position
	Sc3InB					
(70% vol.)	CaTiO ₃	4.66	4.66	4.66	Sc ₃ In _{1:3} B _{0:7}
	Sc ₂ In					
(30% vol.)	N i ₂ In	5.05	5.05	6.30	Sc_2 In

The best agreement for the main phase composition leads to consider that the p{elements B and In are neither fully ordered nor random ly distributed, with about 0.70 In and 0.30 B atom on the 1a site, then 0.65 In and 0.35 B atom on the 1b site of the space group Pm-3m. C onsideration for such a type of atom ic disordering was already reported in literature [21]. Both the compositions of the two compounds (3-1-1 and 2-1) con rm that boron is a di cult element to combine, thus the remaining boron should be detected in the XRD pattern, unless it is di cult to evidence e ectively as a very light and often poorly crystallised element. Susceptibility and resistivity measurements were made using a a.c. susceptometer in temperature ranging from 50 to 2 K.M illimeter sized pieces of the ingot were measured successively and lead to the same results. A typical record is shown on Figure 3, thus revealing the onset of a superconducting state down to 4.4 K, the transition being very sharp with no detectable hysteresis loop. A change in the resistivity trace was also observed simultaneously.

FIG.3: A.c. susceptibility trace revealing the transition to superconducting state.



Unexpectedly, the rest of the ingot and the sm all pieces rapidly change their brittle and bright aspects after several hours let in am bient atm osphere. Besides, a tentative to melt twice the main parts of the initial ingot was made, but at this time no evidence for any superconducting transition was found. Then, several new syntheses were undertaken, thus operating as possible sim ilarly as for the rst one procedure. Again, the new ingots we obtained do not display any transition down to 2 K. As revealed by the theoretical derivations (see below), the superconducting state and the related transition look fairly dependant on the p{elem ent ordering and the stoichiom etry in the 1a and 1b sites. So, we anticipate that during and after the di erent melts, the new sam ples do not exhibit the same atom ordering as it was resulting from the rst attempt. New syntheses are now scheduled to be undertaken using di erent m ethods and techniques in order to achieve optim ized compounds.

Because of experim ental problem s with synthesis, effect of boron site vacancy on electronic structure near E_F and superconducting properties was simulated using KKR method with coherent potential approximation (CPA). We have found signi cant change in values not only for B, but also for Sc, i.e. for 7% boron deciency (Sc₃InB_{0:93}), employing the same values of h! $\frac{2}{1}$ i, total decreased over 30% to 0.62, which resulted in $T_{\rm c}$ ' 4 K . In $\rm Sc_3\,InB_{\,0.85}$ coupling constant is so small 0:4), T_c < 0:5 K seems to be below the standard (low {tem perature m easurem ents. Sim ilar decrease (but less rapid than in the case of B vacancy) of critical param eterswasdetected from KKR-CPA analysiswhen antisite In/B disorder increased.

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- [22] de nition: h! ${}^{n}i = {}^{R} {}^{!n} {}^{2}F (!)d! = {}^{1}{}^{2}F (!)d! {}^{'}$ ${}^{!n} {}^{1}F (!)d! = {}^{!}F (!)d!, if {}^{2}(!) {}^{'}$ const:, where
 - 2 (!) is the electron {phonon interaction coe cient.